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Principle of Communications (MU-IT)

Write short notes on : Properties of Fourier transforms. May 11. Dec. 11

ne of the important properties of the Fourier transform are listed as follows:

Linearity or superposition Duality or sym Time shifting Frequency shifting

Area under X (f) Differentiation in time domain Integration in time domain

Conjugate function (Multiplication theorem) Convolution theorem.

Area under x (t) Let us understand these properties one-by-one.

Property 1 : Linearity or Superposition :

If $x_1(t) \stackrel{F}{\longleftrightarrow} X_1(f)$ and $x_2(t) \stackrel{F}{\longleftrightarrow} X_2(f)$ represent the Fourier

transform pairs and if
$$a_1$$
 and a_2 are constants then we can write,
$$\begin{bmatrix} a_1 \ x_1 \ (t) + a_2 \ x_2 \ (t) \end{bmatrix} \qquad \stackrel{F}{\longmapsto} \begin{bmatrix} a_1 \ X_1 \ (t) + a_2 \ X_2 \ (t) \end{bmatrix} \qquad \dots$$

That means the linear combination of inputs gets transformed into linear combination of their Fourier transforms.

This property can be used to obtain the Fourier transform of a complicated function say x(t) by decomposing it in the form of sum of simpler functions, say x_1 (t) and x_2 (t).

Property 2 : Time Scaling :

- x (αt) represents a time scaled signal and X (f / α) represents the frequency scaled signal or scaled frequency spect
- For α < 1, x (α) represents a compressed signal but X (f / α) represents an expanded version of X (f).
- And for $\alpha > 1$, x (α t) will be an expanded signal in the time domain. But its Fourier transform X (f/α) represents a compressed version of X (f).

" α " being a constant, can be positive or negative. i.e. $\alpha > 0$ or $\alpha < 0$. Let us find the F.T. considering both the possibilities.

Property 3: Duality or Symmetry Property:

This property states that, if $x(t) \stackrel{F}{\longleftrightarrow} X(-f)$

Then
$$X(t) \stackrel{F}{\longleftrightarrow} x(-f)$$

i.e. t and f can be interchanged.

Meaning

- In the term x(t), "x" represents the shape of the signal and "t" shows that the variable is time.
- And in the term X (- f), "X" represents the shape of the spectrum and "f" shows that the variable is frequency.
- 3. The Duality theorem tell us that if $x(t) \stackrel{F}{\longleftrightarrow} X(-f)$ then the shape of the signal in the time domain and the shape of the spectrum can be interchanged.

Property 4: Time Shifting

The time shifting property states that if x (t) and X (f) form a Fourier transform pair then,

$$x (t - t_d) \stackrel{F}{\longleftrightarrow} e^{-j2\pi t_d} X (t) \qquad ...(3)$$

Here the signal x $(t-t_d)$ is a time shifted signal. It is the same signal x (t) only shifted in time.

Property 5 : Area under x(t)

This property states that the area under the curve x(t) equals the value of its Fourier transform at f=0.

i.e. if
$$x(t) \stackrel{F}{\longleftrightarrow} X(f)$$
 then,

Area under
$$x(t) = \int_{-\infty}^{\infty} x(t) dt = X(0)$$
 ...(

Area under $x(t) = \int_{-\infty}^{\infty} x(t) dt$

$$= \int_{-\infty}^{\infty} x(t) e^{-j2\pi it} dt at f = 0.$$

$$= X(f) at f = 0$$

.. Area under x (t) = X (0).

Property 6: Area under X (f)

If $x(t) \stackrel{F}{\longleftrightarrow} X(f)$ then the area under X(f) is equal to the value of signal x(t) at t = 0.

That means if $x(t) \stackrel{F}{\longleftrightarrow} X(f)$ then,

Area under
$$X(f) = \int_{-\infty}^{\infty} X(f) \cdot df = x(0)$$
 ...(5)

Proof: By definition of inverse Fourier transform,

$$x(t) = \int_{-\infty}^{\infty} X(f) \cdot e^{j 2\pi t t} df$$

Substitute t = 0 in this equation to get,

$$x(0) = \int_{0}^{\infty} X(f) \cdot e^{0} df = \int_{0}^{\infty} X(f) dt$$

The RHS of this equation is the area under X (f). Hence the property is proved

Property 7: Frequency Shifting

The frequency shifting characteristics states that if x(t) and X(f) form a Fourier transform pair then,

$$e^{j2\pi f_c t} \times (t) \stackrel{F}{\longleftrightarrow} \times (f - f_c)$$
 ...(6)

Here fc is a real constant.

Proof:

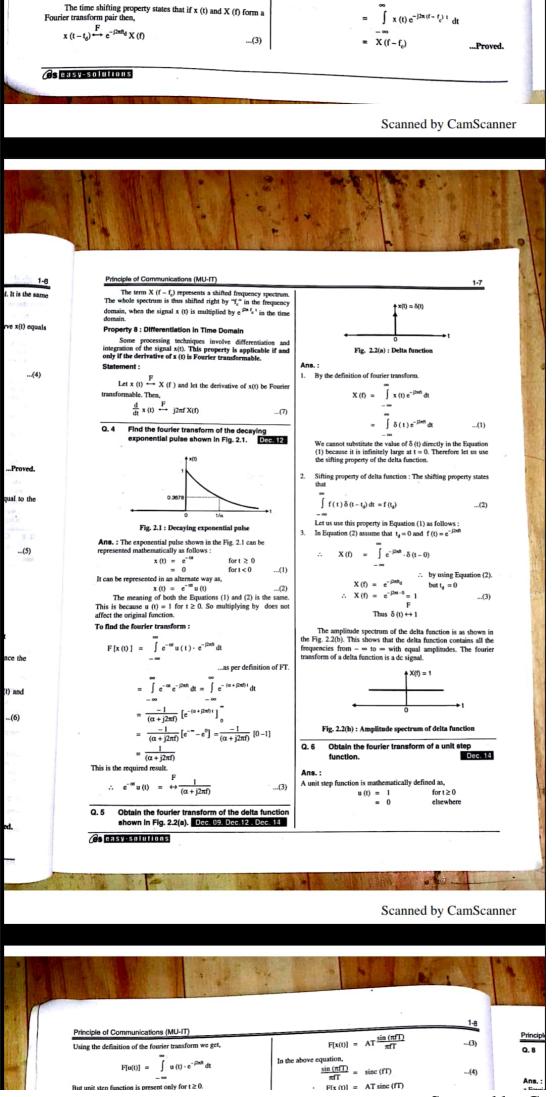
...(2)

$$F\left[e^{j2\pi f_c^{-1}} x\left(t\right)\right] = \int_{-\infty}^{\infty} e^{j2\pi f_c^{-1}} x\left(t\right) e^{-j2\pi f_1^{-1}} dt$$

$$= \int_{-\infty}^{\infty} x\left(t\right) e^{-j2\pi (f_c^{-1}f_c^{-1})} dt$$

$$= X\left(f_c^{-1}f_c^{-1}\right) \qquad \text{w.Proved.}$$

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 $F[x(t)] = \int_{0}^{\infty} e^{-\alpha t} u(t) \cdot e^{-j2\pi\hbar} dt$...as per definition of FT. ...(6) $= \frac{1}{(\alpha + j2\pi f)}$ This is the required result. $\therefore \quad e^{-\alpha t} u (t) \quad = \quad \leftrightarrow \frac{1}{(\alpha + j2\pi f)}$ Q. 5 Obtain the fourier transform of the delta function shown in Fig. 2.2(a). Dec. 09. Dec.12. Dec. 14 Ca easy-solutions Principle of Communications (MU-IT) Using the definition of the fourier transform we get, $F[u(t)] = \int u(t) \cdot e^{-j2\pi\hbar} dt$ But unit step function is present only for $t \ge 0$. :. $F[u(t)] = \int_{0}^{\infty} 1 \cdot e^{-j2\pi i t} dt = \frac{1}{-j2\pi i} \left[e^{-j2\pi i t} \right]_{0}^{\infty}$ $= \frac{1}{-j2\pi f} [e^{-x} - e^{0}]$ $\therefore F[u(t)] = \frac{1}{-j2\pi f} [0 - 1] = \frac{1}{j2\pi f}$ $u(t) \leftrightarrow \frac{1}{j2\pi f}$ Obtain the fourier transform of a rectangular pulse of duration T and amplitude A as shown in Fig. 2.3(a). Dec. 10

Ans.: The rectangular pulse shown in Fig. 2.3(a) can be expressed mathematically as,

rect (VT) = A for $-T/2 \le t \le T/2$ = 0 elsewhere

This is also known as the gate function. Therefore the fourier

 $F[x(t)] = X(f) = \int x(t) \cdot e^{-j2\pi ft} dt$

As per the Euler's theorem, $\sin \theta = \frac{e^{j\theta} - e^{-j}}{2i}$

we get, $F[x(t)] = \frac{A}{\pi f} [\sin (\pi f T)]$

Multiply and divide the RHS of Equation (2) by T to get,

Applying this to Equation (1),

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The amplitude spectrum of the delta function is as shown in the Fig. 2.2(b). This shows that the delta function contains all the frequencies from $-\infty$ to ∞ with equal amplitudes. The fourier transform of a delta function is a dc signal.

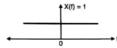


Fig. 2.2(b): Amplitude spectrum of delta function

Q. 6 Obtain the fourier transform of a unit step

Ans.:

...(3)

A unit step function is mathematically defined as,

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Ans. a Four

signa

 $F[x(t)] = AT \frac{\sin(\pi f T)}{\pi f T}$ In the above equation,

$$\frac{\sin(\pi TT)}{\pi TT} = \text{sinc}(fT) \qquad \dots (4)$$

$$\therefore F[x(t)] = AT \text{sinc}(fT)$$

$$F$$

Thus the rectangular pulse transforms into a sinc function. Amplitude spectrum

The amplitude spectrum of the rectangular function is as shown in Fig. $2.3(\mathrm{b})$.

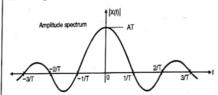


Fig. 2. 3(b): Amplitude spectrum of a rectangular pulse

As we already know,

sinc(0) = 1:. AT sinc (0) = AT

The sinc function will have zero value for the following values of "IT":

Sinc (FT) = 0 for fT = ±1, ±2, ±3,
i.e. for f = ±
$$\frac{1}{T}$$
, ± $\frac{2}{T}$, ± $\frac{3}{T}$

The phase spectrum has not been shown as it has zero value for all the values of f.

To absorb negative values of I X (f) I in the phase shift

The negative amplitude of the amplitude spectrum | X (f) | can be made positive by introducing a phase shift of ± 180° in the phase spectrum. This is as shown in Fig. 2.3(c). A negative phase shift for positive frequency and positive phase shift for the negative frequency is introduced in order to maintain symmetry of the phase

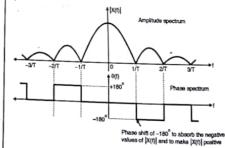


Fig. 2.3(c): Amplitude and phase spectrums for a rectangular

pulse. Negative values of | X (f) | have been absorbed in the additional phase shift of $\pm\,180^{\rm o}$ in the phase spectrum

Applying this to Equation (1), we get, $F[x(t)] = \frac{A}{\pi f} [\sin (\pi f T)]$...(2) Multiply and divide the RHS of Equation (2) by T to get,

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-(3)

_(4)

(f) I

Phase shift of -180° to absorb the negative values of |X(f)| and to make |X(f)| positive

Fig. 2.3(c): Amplitude and phase spectrums for a rectangular pulse. Negative values of $\mid X\left(f\right)\mid$ have been absorbed in the additional phase shift of \pm 180° in the phase spectrum

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Q. 8 State and prove the properties of Fourier transform : Time shifting. May 19, May 10,

Dec. 10. Dec. 13. Dec. 15. May 16

Ans.: The time shifting property states that if x (t) and X (f) form a Fourier transform pair then,

Here the signal $x(t-t_d)$ is a time shifted signal. It is the same signal x(t) only shifted in time.

$$F\left[x\left(t-t_{g}\right)\right] = \int_{-\infty}^{\infty} x\left(t-t_{g}\right) \cdot e^{-\beta mt} dt \qquad ...(2)$$

$$Let \left(t-t_{g}\right) = \tau,$$

$$\therefore \quad t = t_{g} + \tau$$

$$\therefore \quad dt = d\tau.$$

Substituting these values in Equation (1) we get,

$$\begin{split} F\left[x\left(t-t_{d}\right)\right] &= \int\limits_{-\infty}^{\infty} x\left(\tau\right) \cdot e^{-j2\pi i\left(t_{d}+\tau\right)} \, d\tau \\ &= e^{-j2\pi i t_{d}} \int\limits_{-\infty}^{\infty} x\left(\tau\right) e^{-j2\pi i \tau} \, d\tau \end{split}$$

Significance of time shifting in communication systems

If signal x(t) is transmitted by a transmitter, then due to the distance travelled, this signal becomes a time delayed signal x ($t-t_p$) when it reaches the receiver.

The time delay "t_d" is dependent on the distance between the transmitter and the receiver.

The time shifting property explains the effect of such time shifting on the spectrum of the signal. It tells us that there is no effect of time shifting on the amplitude spectrum but there is an additional phase shift of $-2\pi f t_d$.

Q. 9 State and prove the differentiation in time domain property of the Fourier Transform.

Dec. 15. Dec. 16

Ans. : Some processing techniques involve differentiation and integration of the signal x(t). This property is applicable if and only if the derivative of x (t) is Fourier transformable.

Statement : Let $x(t) \stackrel{F}{\longleftrightarrow} X(f)$ and let the derivative of x(t) be Fourier transformable. Then,

$$\frac{d}{dt} \times (t) \xrightarrow{F} j2\pi f X(f) \qquad ...(1)$$

Proof: By the definition of inverse Fourier transform,

$$x(t) = \int_{-\infty}^{\infty} X(f) e^{+j2\pi f t} df$$

Therefore $\frac{d}{dt} x(t) = \frac{d}{dt} \left[\int_{-\infty}^{\infty} X(t) e^{-tPxt_1} dt \right]$ $= \int_{-\infty}^{\infty} X(t) \left(\frac{d}{dt} e^{-tPxt_1} \right) dt$ $\frac{d}{dt} x(t) = \int_{-\infty}^{\infty} \left[X(t) \cdot j2\pi t \right] e^{-tPxt_1} dt$

As per the definition of the inverse Fourier transform the term inside the square bracket must be the Fourier transform of $\frac{d}{dt}$ x (t).

Meaning

Differentiating the signal in time domain is equivalent to multiplying its Fourier transform by $(2\pi f)$ in the frequency domain. Thus differentiation will enhance the high frequency components since $|2\pi f| X(f) > |X(f)|$.

Q. 10 Prove time convolution property of Fourier

May 09, May 10, Dec. 10, May 12, Dec. 13, May 16

Ans.: This property states that the convolution of signals in the time domain will be transformed into the multiplication of their Fourier transforms in the frequency domain.

i.e.
$$[x_1(t) * x_2(t)] \xrightarrow{F} X_1(f) X_2(f)$$
 ...(1)

Proof: The convolution of the two signals in the time domain is defined as,

$$X_1(t) * x_2(t) = \int_0^\infty x_1(\lambda) \cdot x_2(t-\lambda) d\lambda$$
 ...(2)

Taking the Fourier transform of the convolution

$$F\left[x_{1}\left(t\right) * x_{2}\left(t\right)\right] = \int_{-\infty}^{\infty} \left[\int_{-\infty}^{\infty} x_{1}\left(\lambda\right) \cdot x_{2}\left(t-\lambda\right) d\lambda\right] e^{-j2\pi t_{1}} dt ...(3)$$

Multiply and divide the RHS of the Equation (2) by $e^{-j2\pi i \lambda}$ to

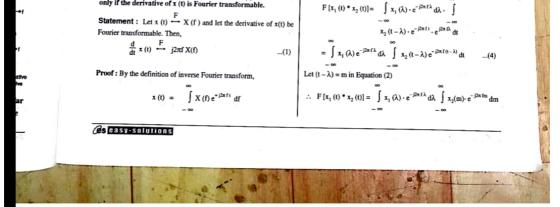
$$F[x_1(t) * x_2(t)] = \int_{-\infty}^{\infty} x_1(\lambda) \cdot e^{-j2\pi t \lambda} d\lambda \cdot \int_{-\infty}^{\infty} x_2(t-\lambda) \cdot e^{-j2\pi t \lambda} \cdot e^{j2\pi t \lambda} dt$$

$$= \int_{-\infty}^{\infty} x_1(\lambda) e^{-j2\pi t \lambda} d\lambda \int_{-\infty}^{\infty} x_2(t-\lambda) e^{-j2\pi t(t-\lambda)} dt \qquad ...(4)$$

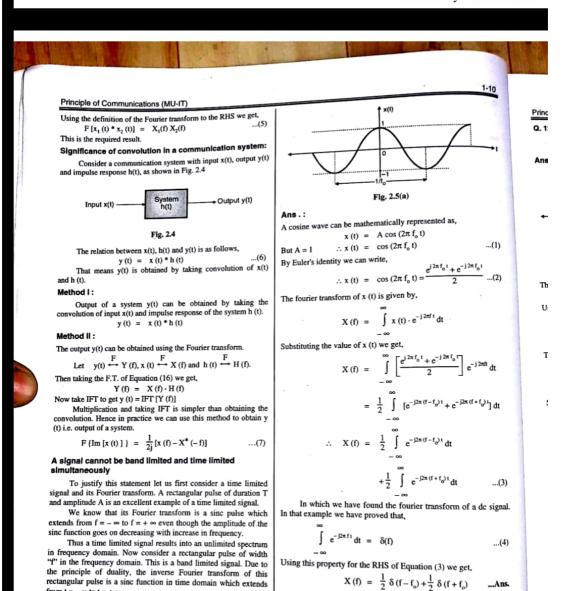
Let $(t - \lambda) = m$ in Equation (2)

$$\therefore F[x_1(t) \cdot x_2(t)] = \int_{-\infty}^{\infty} x_1(\lambda) \cdot e^{-j2\pi t \lambda} d\lambda \int_{-\infty}^{\infty} x_2(m) \cdot e^{-j2\pi t m} dm$$

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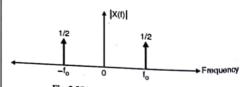


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Obtain the fourier transform of a cosine wave having a frequency fo and peak amplitude of unity and plot its spectrum. Refer Fig. 2.5(a).

Thus band limiting in the frequency domain results in a "time unlimited" signal in the time domain. Thus a signal cannot be band



shows that two impulses are present one at f_o and the other at $-f_o$.

The frequency spectrum is as shown in the Fig. 2.5(b) which

Fig. 2.5(b): Spectrum of a cosine wave

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from $t = -\infty$ to $t = +\infty$.

limited or time limited simultaneously.

Chapter 3 : Noise

Classify and explain the various noises that Dec. 03, May 11 affect communications.

Ans. :

Noise can be divided into two broad categories:

External noise of uncorrelated noise

Internal noise or correlated noise or fundamental noise.

The classification of noise sources is shown in Fig. 3.1

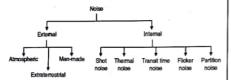


Fig. 3.1

External Noise (Uncorrelated Noise)

It is defined as the noise that is generated outside the device or circuit. As shown in Fig. 3.1., the external noise can be of three

- Atmospheric noise
- Extraterrestrial and
- Man made noise

Fundamental or Internal Noise:

The fundamental sources of noise are within the electronic equipment. They are called fundamental sources because they are the integral part of the physical nature of the material used for making electronic components. This type of noise follows certain rules. Therefore it can be eliminated by properly designing the electronic circuits and equipments.

Classify and explain the various noises that affect communications. May 11

Ans. :

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It is defined as the noise that is generated outside the device or circuit. As shown in Fig. 3.1., the external noise can be of three types:

- Atmospheric noise
- 2 Extraterrestrial and
- Man made noise

1. Atmospheric noise

- This type of noise gets produced within the Earth's atmosphere. The common source of this type of noise is lightning. This type of noise is in the form of ilses or spikes which covers a wide frequency band typically upto 30 MHz.
- The sputtering, cracking etc heard from the loud speakers of radio is due to atmospheric noise.

This type of noise becomes insignificant above (iii) 30 MHz

Extraterrestrial noise

- This type of noise originates from the sources which exist outside the Earth's atmosphere. Hence this noise is also called as deep space noise.
- The noise originating from the sun and the outer space is known as Extraterrestrial Noise.
- The extraterrestrial noise can be sub-divided into two groups: (a) Solar noise (b) Cosmic noise
- Our sun being a large body at very high temperatures radiates a lot of noise. The noise radiation from sun varies with the temperature changes on its surface.
- The temperature changes follow a cycle of 11 years hence the cycle of great electrical disturbances (noise) also repeats after every 11 years.
- (vi) The cosmic noise comes from the stars. This is identical to the noise radiated by sun because stars also are large hot bodies.
- (vii) This noise is called as black body noise or thermal noise and it is distributed uniformly over the entire sky. The noise also gets originated from the center of our galaxy, other galaxies and special type of stars such as "Quasars" and "Pulsars".

3. Man made noise (Industrial noise)

The man made noise is generated due to the make and break process in a current carrying circuit. The examples are the electrical motors, welding machines, ignition system of the automobiles, thyristorised high current circuits, fluorescent lights, switching gears etc. This type of noise is also called as industrial noise.

What are the types of Internal Nosie?

Ans.: The fundamental noise sources produce different types of noise. They are as follows:

- Thermal noise
- Shot noise
- Partition noise
- Low frequency or flicker, noise.
- High frequency or transit time, noise.
- Avalanche noise. Burst noise

Let us know them one by one.

1. Shot Noise

- The shot noise is produced due to shot effect. Due to the shot effect, shot noise is produced in all the amplifying devices or for that matter in all the active
- The shot noise is produced due to the random variations in the arrival of electrons (or holes) at the output electrode of an amplifying device.
- Therefore it appears as a randomly varying noise current superimposed on the output. The shot noise "sounds" like a shower of lead shots falling on a metal sheet if amplified and passed through a loud speaker.

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- The shot noise has a uniform spectral density like thermal noise. The exact formula for the shot noise can be obtained only for diodes.
- For all other devices an approximate equation is stated. The mean square shot noise current for a diode is given

If the time taken by an electron to travel from the emitter to the collector of a transistor becomes comparable to the time period of the signal which is being amplified then the transit time effect will take place.

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Principle of Communications (MU-IT)

- (iv) The shot noise has a uniform spectral density like thermal noise. The exact formula for the shot noise can be obtained only for diodes.
- (v) For all other devices an approximate equation is stated.

 The mean square shot noise current for a diode is given

where, I_{dc} = Direct current across the junction (in Amp)

q = Electron charge

= 1.6 × 10⁻¹⁹ C. B = Effective noise bandwidth in Hz.

For the amplifying devices the shot noise is:

- Inversely proportional to the transconductance of the device.
- 2. Directly proportional to the output current.

2. Partition Noise

Partition noise is generated when the current gets divided between two or more paths. It is generated due to the random fluctuations in the division. Therefore the partition noise in a transistor will be higher than that in a diode. The devices like gallium arsenide FET draw almost zero gate bias current, hence keeping the partition noise to its minimum value.

3. Low Frequency or Flicker Noise :

The flicker noise will appear at frequencies below a few kilohertz. It is sometimes called as "1/f" noise. In the semiconductor devices, the flicker noise is generated due to the fluctuations in the carrier density (i.e. density of electrons and holes)

These fluctuations in the carrier density will cause the fluctuations in the conductivity of the material. This will produce a fluctuating voltage drop when a direct current flows through a device. This fluctuating voltage is called as flicker noise voltage.

The mean square value of flicker noise voltage is proportional to the square of direct current flowing through the device.

4. Thermal Noise or Johnson Noise

The free electrons within a conductor are always in random motion. This random motion is due to the thermal energy received by them. The distribution of these free electrons within a conductor at a given instant of time is not uniform.

It is possible that an excess number of electrons may appear at one end or the other of the conductor. The average voltage resulting from this non-uniform distribution is zero but the average power is not zero.

As this power has appeared as a result of the thermal energy, it is called as the "thermal noise power".

The average thermal noise power is given by,

 $P_n = k \text{ TB Watts}$

k = Boltzmann's constant

= 1.38×10^{-23} Joules/Kelvin.

B = Bandwidth of the noise spectrum (Hz).

T = Temperature of the conductor, °Kelvin

Equation (2) indicates that a conductor operated at a finite temperature can work as a generator of electrical energy. The thermal noise power P_n is proportional to the noise BW and conductor temperature.

5. High Frequency or Transit Time Noise

If the time taken by an electron to travel from the emitter to the collector of a transistor becomes comparable to the time period of the signal which is being amplified then the transit time effect will take place.

This effect is observed at very high frequencies typically in the VHF range. Due to the transit time effect some of the carriers may diffuse back to the emitter.

This gives rise to an input admittance, the conductance component of which increases with frequency.

The very small currents induced in the input of the device by means of the random fluctuations in the output current will create random noise at high frequencies. Once this noise appears, it goes on increasing with frequency at a rate of 6 dB per octave.

6. Correlated Noise

This is the form of internal noise. It is present in the circuit if and only if the signal is present. This is how it is correlated with the signal and hence called as the correlated noise.

In other words this type of noise will be absent if the signal is absent. Correlated noise is produced due to the nonlinear amplification process.

The types of correlated noise are:

Harmonic distortion 2. Intermodulation distortion

Both these are basically the nonlinear distortions.

All the electronic circuits exhibit a nonlinear behaviour and hence produce nonlinear distortions.

7. Impulse Noise

This type of noise is in the form of spikes of high amplitude and short duration, in the total noise spectrum. The shapes of these noise pulse are undefined as shown in Fig. 3.2

This type of noise is produced by electromechanical relays and solenoids, electric motors, fluorescent lights, ignition systems of automobiles and lightning.

The impulse noise produces a sharp popping or crackling sound in the audio circuits and produces errors in the data communication circuits.

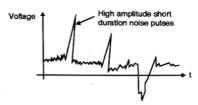


Fig. 3.2 : Impulse noise

8. Interference

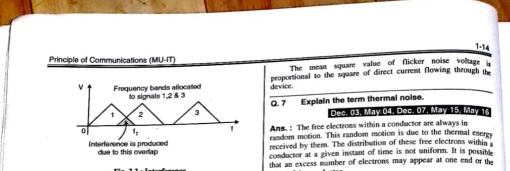
...(2)

This is a type of external noise. The meaning of the word "Interference" is "to disturb or detract from".

The interference is produced when information signal from one source produces frequencies that fall outside their allocated frequency band and interfere with the frequency band allocated to some other information signal as shown in Fig. 3.3. Interferences take place in the radio frequency spectrum when harmonics or cross-product frequencies from one source fall into the passband of the other source.

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 $P_n = k TB Watts$ where. k = Boltzmann's constant

= 1.38×10^{-23} Joules/Kelvin.

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Interference

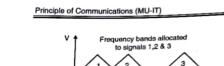
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terference is produc due to this overlap

Fig. 3.3: Interference

Explain the terms : Shot noise and Equivalent noise temperature

Dec. 04, Dec. 13, May 15, Dec. 15

Ans.: The shot noise is produced due to shot effect. Due to the shot effect, shot noise is produced in all the amplifying devices or for that matter in all the active devices.

The shot noise is produced due to the random variations in the arrival of electrons (or holes) at the output electrode of an amplifying device.

Therefore it appears as a randomly varying noise current superimposed on the output. The shot noise "sounds" like a shower of lead shots falling on a metal sheet if amplified and passed through a loud speaker.

The shot noise has a uniform spectral density like thermal noise. The exact formula for the shot noise can be obtained only for diodes. For all other devices an approximate equation is stated. The mean square shot noise current for a diode is given as :

$$I_n^2 = 2 I_{dc} q B Amperes^2 \qquad ...(1)$$

where, I_{de} = Direct current across the junction (in Amp)

q = Electron charge = 1.6×10^{-19} C.

B = Effective noise bandwidth in Hz.

For the amplifying devices the shot noise is

1. Inversely proportional to the trans conductance of the device.

Directly proportional to the output current.

Q. 5 Write a short note on : Partition Noise.

Partition noise is generated when the current gets divided between two or more paths. It is generated due to the random fluctuations in the division. Therefore, the partition noise in a transistor will be higher than that in a diode.

The devices like gallium arsenide FET draw almost zero gate bias current, hence keeping the partition noise to its minimum

Write a short note on : Low Frequency or Flicker Noise.

Ans. : The flicker noise will appear at frequencies below a few kilohertz. It is sometimes called as "1/f" noise

In the semiconductor devices, the flicker noise is generated due to the fluctuations in the carrier density (i.e. density of electrons and holes).

These fluctuations in the carrier density will cause the fluctuations in the conductivity of the material. This will produce a fluctuating voltage drop when a direct current flows through a device. This fluctuating voltage is called as flicker noise voltage.

The mean square value of flicker noise voltage The mean square value of lifeker house voltage in proportional to the square of direct current flowing through the

Explain the term thermal noise.

Dec. 03, May 04, Dec. 07, May 15, May 16

Ans.: The free electrons within a conductor are always in Ans.: The free electrons within a conductor at a different energy random motion. This random motion is due to the thermal energy received by them. The distribution of these free electrons within a conductor at a given instant of time is not uniform. It is possible that an excess number of electrons may appear at one end or the other of the conductor.

The average voltage resulting from this non-uniform distribution is zero but the average power is not zero.

As this power has appeared as a result of the thermal energy, it is called as the "thermal noise power".

The average thermal noise power is given by,

$$P_n = k TB Watts$$
 ...(1)
where, $k = Boltzmann's constant$

= 1.38×10^{-23} Joules/Kelvin.

B = Bandwidth of the noise spectrum (Hz).

T = Temperature of the conductor, oKelvin

Equation (1) indicates that a conductor operated at a finite temperature can work as a generator of electrical energy.

The thermal noise power P_n is proportional to the noise BW and conductor temperature.

Write a short note on : High Frequency or Transit Time Noise

Ans.: If the time taken by an electron to travel from the emitter to the collector of a transistor becomes comparable to the time period of the signal which is being amplified then the transit time effect will take place.

This effect is observed at very high frequencies typically in the VHF range. Due to the transit time effect some of the carriers may diffuse back to the emitter. This gives rise to an input admittance, the conductance component of which increases with

The very small currents induced in the input of the device by means of the random fluctuations in the output current will create random noise at high frequencies. Once this noise appears, it goes on increasing with frequency at a rate of 6 dB per octave.

An amplifier has a bandwidth of 4 MHz with 10 $k\Omega$ as the input resistor. Calculate the rms noise voltage at the input to this amplifier if the room temperature is 25°C. Dec.16

Ans. : Given : B = 4 MHz, $R_i = 10$ k Ω , T = 25°C = 298° K Rms noise voltage $V_n = \sqrt{4 \text{ kTBR}}$

$$= \sqrt{4 \times 1.38 \times 10^{-23} \times 298 \times 4 \times 10^6 \times 10 \times 10^3}$$

$$V_n = 25.65 \,\mu\text{V}$$

Q. 10 Write a short note on : Correlated Noise.

May 15

Ans.: This is the form of internal noise. It is present in the circuit if and only if the signal is present. This is how it is correlated with the signal and hence called as the correlated noise. In other words this type of noise will be absent if the signal is absent. Correlated noise is produced due to the nonlinear amplification process.

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Principle of Communications (MU-IT)

Q. 11 Write short notes on White noise

May 12, Dec. 13

Ans.: The effect of "white" noise on the performance of different communication systems.

"White" noise is the noise whose power spectral density is uniform over the entire frequency range of interest, as shown in Fig. 3.6.

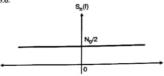


Fig. 3.6: Power spectral density of white noise

Why is it called as white noise?

The white noise contains all the frequency components in equal proportion. This is analogous with white light which is a superposition of all visible spectral components.

Why is it called as gaussian noise?

The white noise has a Gaussian distribution. That means the PDF of white noise has the shape of Gaussian PDF. Therefore it is called as gaussian noise.

Power spectral density of white noise

As shown in Fig. 3.6 the power spectral density (psd) of a white noise is given by,

$$S_n(f) = \frac{N_0}{2}$$
 ...(1)

This equation shows that the power spectral density of white noise is independent of frequency. As N_0 is constant, the psd is uniform over the entire frequency range including the positive as well as the negative frequencies. N_0 in Equation (3.3.11) is defined

$$N_0 = KT_c$$
 ...(2) where, $K = Boltzmann's constant$ and

T_e = Equivalent noise temperature of the system.

Example of white noise

The best example of white noise is the thermal or Johnson

Q. 12 Define the following term: Noise bandwidth.

Dec. 03. Dec. 12. May 15. May 16

Ans. : Assume that a white noise is present at the input of a receiver (filter). Let the filter have a transfer function H(f) as shown in Fig. 3.7.

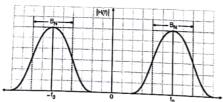


Fig. 3.7: Noise bandwidth of a filter

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This filter is being used to reduce the noise power actually This filter is being used to reduce the noise power actually passed on to the receiver. Now draw the frequency response of an ideal (rectangular) filter as shown by the dotted plot in Fig. 3.7. The center frequency of this ideal filter also in f₀.

Let the bandwidth "B_N" of the ideal filter be adjusted in such a way that the noise output power of the ideal filter is exactly equal to the noise output power of a real R-C filter.

Then B_N is called as the noise bandwidth of the real filter.

Thus the noise bandwidth " B_N " is defined as the bandwidth of an ideal (rectangular) filter which passes the same noise power as passed by the real filter.

Q. 13 Define the following term : Signal to noise ratio.

Dec. 03, Dec. 04, May 06, May 09, Dec. 09, May 15. May 16

Ans.: In the communication systems the comparison of signal power with the noise power at the same point is important, to ensure that the noise at that point is not excessively large.

It is defined as the ratio of signal power to the noise power at the same point.

$$\therefore \quad \frac{S}{N} = \frac{P_s}{P_n} \qquad ...(1)$$

Where,

P_a = Signal power P_n = Noise power at the same point.

The signal to noise ratio is normally expressed in dB and the typical values of S/N ratio range from about 10 dB to 90 dB. Higher the value of S/N ratio better the system performance in presence of noise

$$S/N (dB) = 10 \log_{10} (P_a / P_n)$$
 ...(2)

The powers can be expressed in terms of signal and noise voltages as follows:

$$P_s = \frac{V_s^2}{R}$$
 and $P_n = \frac{V_n^2}{R}$

where V_s = Signal voltage and V_n = Noise voltage.

$$\therefore \frac{S}{N} = \frac{V_{s}^{2}/R}{V_{n}^{2}/R} = \left(\frac{V_{s}}{V_{n}}\right)^{2} ...(3)$$

The signal to noise ratio in dB is given by.

$$(S/N)_{dB} = 10 \log_{10} \left[\frac{V_s}{V_n} \right]^2 = 20 \log_{10} \left[\frac{V_s}{V_n} \right] ...(4)$$

All the possible efforts are made to keep the signal to noise ratio as high as possible, under all the operating conditions.

Although the signal to noise ratio is a fundamental characteristics of a communication system it is often difficult to measure. In practice instead of measuring S/N, another ratio called (S + N)/N is measured.

What is meant by signal to noise ratio ? Discuss the importance of SNR in radio receivers.

Dec. 04, May 06, May 15

Ans.: The given amplifier is shown in Fig. 3.8. Let us obtain the equivalent circuit for it.

The equivalent circuit is obtained as follows:

Remove the amplifier and calculate the open circuit voltage between points A and B. This is the Thevenin's voltage V_{∞} or V_{TM} and it is denoted by V_s. (See Fig. 3.9(a))

$$\therefore V_a = V_{TH} = \frac{R_i}{R_i + R_s} \times E_s \qquad ...(5)$$

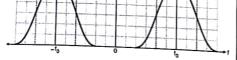
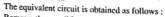


Fig. 3.7: Noise bandwidth of a filter Cs easy-solutions



Remove the amplifier and calculate the open circuit volt. between points A and B. This is the Thevenin's voltage V_{∞} or V_{∞} and it is denoted by V₁. (See Fig. 3.9(a))

$$\therefore V_s = V_{Tit} = \frac{R_i}{R_i + R_s} \times E_s$$

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Principle of Communications (MU-IT)

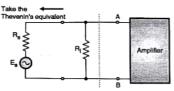
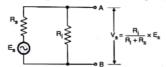
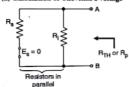


Fig. 3.8 : Given amplifier

Then calculate Thevenin's equivalent resistance $\boldsymbol{R}_{T\!H}$ between A and B with E_s reduced to zero as shown in Fig. 3.9 (b).



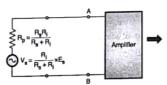
(a) Calculation of Thevenin's voltage



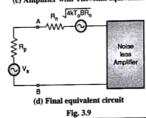
(b) Calculation of Thevenin's resistance Fig. 3.9

From Fig. 3.9(b),
$$R_{TH} = R_p = R_s \parallel R_i = \frac{R_s R_i}{(R_s + R_i)}$$
 ...(6)

Hence the Thevenin's equivalent circuit of the amplifier is as shown in Fig. 3.9(c).



(c) Amplifier with Thevenin equivalent



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Now complete the equivalent circuit as shown in Fig. 3.9 (d) by taking out the noise equivalent resistance R, and the associated noise voltage, outside the amplifier.

Signal to noise ratio

The signal to noise ratio at the input is,

$$SNR_i = \frac{S_i}{N_i}$$

 $S_i = Input signal power = V_i^2$ and $N_i = \text{Input noise power} = V_n^2 = 4 \text{ k } T_o \text{ B } (R_p + R_n)$

$$\therefore SNR_i = \frac{V_s^2}{4 k T_o B (R_p + R_p)} \qquad ...(7)$$

Since the amplifier is noiseless, the SNR at its input and output will be the same.

Then the signal to noise ratio at the amplifier output is,
$$\frac{S}{N} \; = \; \frac{V_s^2}{4 \, (R_p + R_n) \, k \, T_o \, B} \qquad ...(8)$$

Here $(R_p + R_n)$ represents the equivalent resistance producing noise at the input of the amplifier

Q. 15 Define the following term : Noise factor. May 09. Dec. 10. May 12. Dec. 14. May 15

Ans.:

The noise factor (F) of an amplifier or any network is defined in terms of the signal to noise ratio at the input and the output of the system. It is defined as:

$$F = \frac{S/N \text{ ratio at the input}}{S/N \text{ ratio at the output}} ...(1)$$

$$= \frac{P_{si}}{P_{si}} \times \frac{P_{so}}{P_{so}} \qquad ...(2$$

where P_{si} and $P_{ni} = Signal$ and noise power at the input and P_{so} and $P_{no} = Signal$ and noise power at the output.

The temperature to calculate the noise power is assumed to be the room temperature. The S/N at the input will always be greater than that at the output. This is due to the noise added by the amplifier. Therefore the noise factor is the means to measure the amount of noise added and it will always be greater than one. The ideal value of the noise factor is unity.

The noise factor F is sometimes frequency dependent. Then

its value determined at one frequency is known as the spot noise factor and the frequency must be stated along with the spot noise

Q. 16 Define the following term : Noise figure.

Dec. 03, May 09, May 10, Dec. 10, Dec. 14, May 16

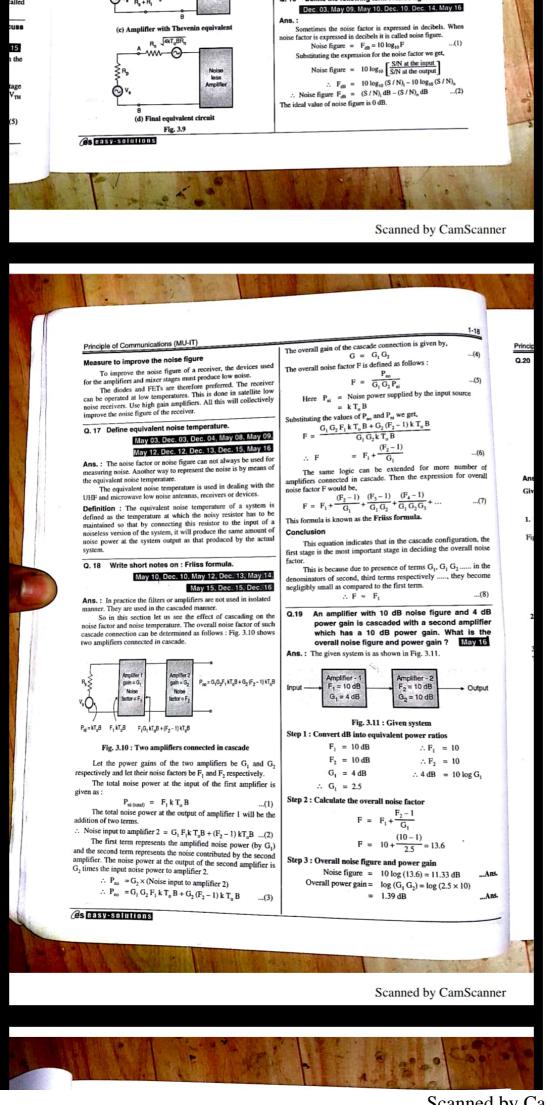
Sometimes the noise factor is expressed in decibels. When noise factor is expressed in decibels it is called noise figure.

Noise figure = $F_{dB} = 10 \log_{10} F$ Substituting the expression for the noise factor we get,

Noise figure = $10 \log_{10} \left[\frac{S/N \text{ at the input}}{S/N \text{ at the output}} \right]$

 $\begin{array}{lll} \therefore & F_{dB} & = & 10 \log_{10} (S \, / \, N)_i - 10 \log_{10} (S \, / \, N)_o \\ \therefore & \text{Noise figure } F_{dB} & = & (S \, / \, N)_i \, dB - (S \, / \, N)_o \, dB \end{array} \quad ... \\ \end{array}$ The ideal value of noise figure is 0 dB.

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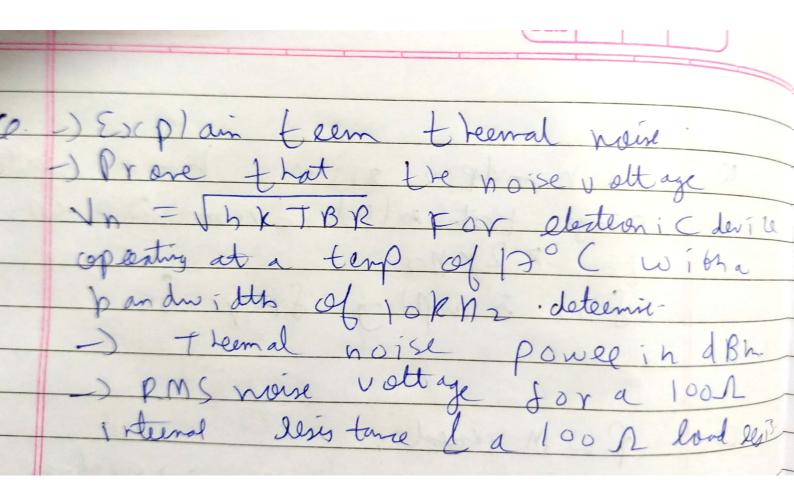
Deeme Egim noise temp
Solve of 6 B & Calmate 1 to

Egim noise temp.

Let To=27°C=300K

Teg=(F-1) To

= 1500°K



Q.20 A three stage amplifier has the following power gains and noise figure (as ratios, not in dB) for each stage:

Calculate the power gain, noise figure and the noise temperature for the entire amplifier, assuming matched conditions.

May	04,	Dec.	07.	Dec.	11

Stage	Power gain	Noise figure	
1	10	2	
2	20	4	
3	30	5	

Ans.:

Given:
$$G_1 = 10$$
, $G_2 = 20$, $G_3 = 30$,
 $F_1 = 2$, $F_2 = 4$, $F_3 = 5$.

1. Draw the block diagram of the system

The block diagram of the cascaded amplifiers is as shown in Fig. 3.12.

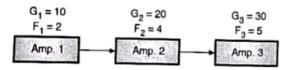


Fig. 3.12: Cascaded amplifier system

2. Overall power gain

$$G = G_1 \times G_2 \times G_3$$

= $10 \times 20 \times 30 = 6000$...Ans.

3. Overall noise figure

The overall noise factor is given by,

$$F = F_1 + \frac{(F_2 - 1)}{G_1} + \frac{(F_3 - 1)}{G_1G_2}$$

$$\therefore F = 2 + \frac{(4 - 1)}{10} + \frac{(5 - 1)}{10 \times 20}$$

$$\therefore F = 2.32 \qquad ...(1)$$

:. Overall noise figure F dB = 10 log₁₀ (2.32)

4. Overall noise temperature

$$T_{eq} = (F-1) T_{o}$$
Let $T_{o} = \text{Room temperature} = 300^{\circ} \text{ K}$

$$\therefore T_{eq} = (2.32-1) \times 300$$

$$\therefore T_{eq} = 396^{\circ} \text{ K} \qquad \text{...Ans.}$$

Q. 21 Explain the term thermal noise. Prove that noise voltage $V_N = \sqrt{4 \text{ kTBR}}$. For electronic device operating at a temperature of 17°C with a bandwidth of 10 kHz, Dec 07. May 11

Determine:

- Thermal noise power in dBm.
- 2. rms noise voltage for a 100 Ω internal resistance and a 100 Ω load resistance.

Ans.: For thermal noise, refer Q.7. For the derivation of noise voltage refer Q.7.

Solution of example :

Given: $T = 17^{\circ} C = 290^{\circ} K$, B = 10 kHz

1. Thermal noise power:

$$P = kTB$$
= 1.28 × 10⁻²³ × 290 × 10 × 10³
= 4.002 × 10⁻¹⁷ W ...Ans.
$$P_{(dBm)} = 10 \log_{10} \left(\frac{4.002 \times 10^{-17}}{1 \times 10^{-3}} \right)$$
= -133.98 dBm ...Ans.

2. Rms noise voltage

Assume that the internal resistance of the device is in series with the load resistance.

∴ R =
$$100 + 100$$

= 200Ω
∴ V_a = \sqrt{kTBR}
= $\sqrt{4.002 \times 10^{-17} \times 200}$
= $8.95 \times 10^{-8} \text{ V}$...Ans.

Q. 22 For three cascaded amplifier stages, each with noise figure of 3dB and power gain of 10 dB, determine the total noise figure.

May 07

Ans.:

$$F_1 = F_2 = F_3 = 3 \text{ dB},$$

 $G_1 = G_2 = G_3 = 10 \text{ dB}$

Step 1 : Convert dB into equivalent power ratios

$$F_1 = F_2 = F_3 = 3 \text{ dB}$$

$$\begin{array}{rcl} \therefore & 3 & = & 10 \log F_1 \\ & \therefore & F_1 & = & 1.995 & = F_2 = F_3 \\ G_1 = G_2 = G_3 = 10 \text{ dB} \\ & \therefore & 10 & = & 10 \log G_1 \end{array}$$

$$\therefore G_1 = 10$$

Step 2: Calculate the overall noise factor Using the Friiss formula,

$$F = F_1 + \frac{(F_2 - 1)}{G_1} + \frac{(F_3 - 1)}{G_1 G_2}$$

$$= 1.995 + \frac{(1.995 - 1)}{10} + \frac{(1.995 - 1)}{100}$$

$$= 1.995 + 0.0995 + 9.95 \times 10^{-3}$$

$$F = 2.0594$$

Step 3: Calculate the overall noise figure

$$F_{dB} = 10 \log_{10} (2.0594)$$

Noise figure = 3.1374 dB ...Ans.